

MSB40A THRU MSB40M

SINGLE-PHASE GLASS PASSIVATED SILICON BRIDGE RECTIFIER

REVERSE VOLTAGE: 50 to 1000 VOLTS FORWARD CURRENT: 4.0 AMPERE

FEATURE

- . Glass passivated junction.
- . Ideal for printed circuit board.
- . Reliable low cost construction utilizing molded plastic technique.
- . High surge current capability.
- . High temperature soldering guaranteed: 260°C/10 seconds at terminals.

MECHANICAL DATA

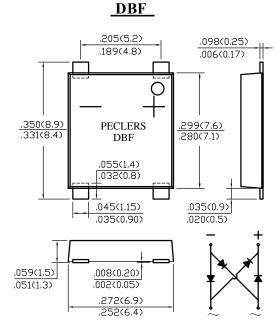
. Case: Molded plastic, DBF

. Epoxy: UL 94V-O rate flame retardant

. Terminals: Leads solderable per MIL-STD-202,

method 208 guaranteed
. Mounting position: Any

• Weight: 0.204g (approximately)



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25° C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	SYM BOL	MSB 40A	MSB 40B	MSB 40D	MSB 40G	MSB 40J	MSB 40K	MSB 40M	units
Maximum Recurrent Peak Reverse Voltage	$V_{ m RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{ m RMS}$	35	70	140	280	420	560	700	V
Maximum DC blocking Voltage	$V_{ m DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward rectified Current @ T _A =40 °C	I _{F(AV)}				4.0				A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rate load (JEDEC method)	$I_{ m FSM}$	150					A		
	/ _E	1.0 1.1							V
Maximum DC Reverse Curren $@T_J = 25^{\circ}\text{C}$ at rated DC blocking voltage $@T_J = 125^{\circ}\text{C}$	$I_{ m R}$	5.0 500.0							μА
Typical Junction Capacitance Per Leg (Note1)	C _J	50							pF
Typical Thermal Resistance (Note2)	$R_{ m JA}$	60							°C /W
	$R_{ m JC}$	10							
Storage Temperature	T _{STG}	-55 to +150							°C
Operating Junction Temperature	$T_{ m J}$	-55 to +150							°C

Note:

- 1. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
- 2. Mounted on glass epoxy PC board with 4×1.5"×1.5" (3.81×3.81 cm) copper pad.



MSB40A THRU MSB40M

SINGLE-PHASE GLASS PASSIVATED SILICON BRIDGE RECTIFIER

RATINGS AND CHARACTERISTIC CURVES

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

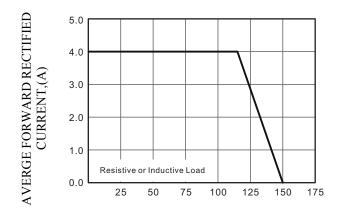
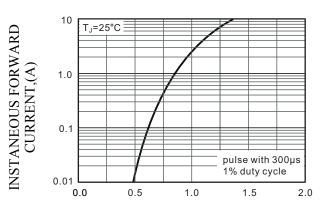


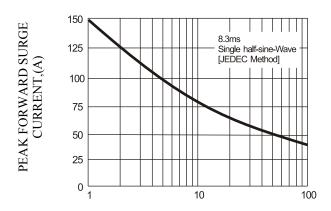
FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



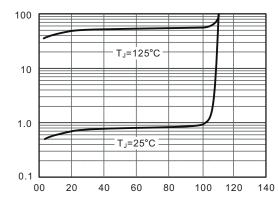
AMBIENT,CASE TEMPERTURE,(℃)

FIG.3-MAXIMUN NON-REPETITIVE FORWARD SURGE CURRENT

INSTANEOUS FORWARD VOLTAGE,(V)
FIG.4-TYPICAL REVERSE CHARACTERISTICS



INSTANEOUS REVERSE CURRENT,(µ A)

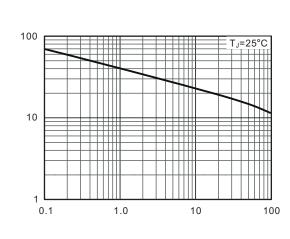


NUMBER OF CYCLES AT 60Hz

PERCENT OF RATED PEAK REVERSE VOLTAGE,(

FIG.5-TYPIAL JUNCTION CAPAOTANCE





REVERCE VOLTAGE,(V)